

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7WG02FC

Dual 2-Input NOR Gate

Features

 High-level output current: I_{OH}/I_{OL} = ±8 mA (min) at V_{CC} = 3 V

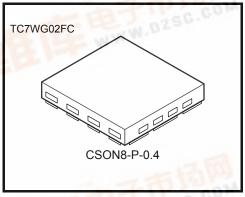
• High-speed operation: t_{pd} = 2.8 ns (typ.)

at $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$

Operating voltage range: V_{CC} = 0.9~3.6 V

5.5-V tolerant inputs

• 3.6-V power down protection outputs



Weight: 0.002 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	-0.5~4.6	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	Vour	-0.5~4.6 (Note 1)	V
	V _{OUT}	-0.5~V _{CC} + 0.5 (Note 2)	V
Input diode current	l _{IK}	-20	mA
Output diode current	lok	-20 (Note 3)	mA
DC output current	lout	±25	mA
DC V _{CC} /GND current	Icc	±50	mA
Power dissipation	PD	150 (Note 4)	mW
Storage temperature	T _{stg}	-65~150	°C

ote: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V_{CC} = 0V

Note 2: High or Low State.

I_{OUT} absolute maximum rating must be observed.

Note 3: Vout < GND

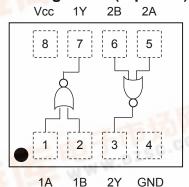
Note 4: Mounted on an FR4 board.

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{ Cu Pad: } 11.56 \text{ mm}^2)$

Marking

G02

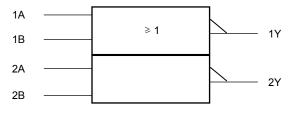
Pin Assignment (top view)



Truth Table

Inp	Outputs	
Α	В	Y
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

IEC Logic Symbol



Operating Ranges

Characteristics	Symbol	Value	Unit		
Power supply voltage	V _{CC}	0.9~3.6	V		
Input voltage	V _{IN}	0~5.5	V		
Outrout valte as	V	0~3.6 (Note 5)	V		
Output voltage	V _{OUT}	0~V _{CC} (Note 6)	V		
Output Current		±8.0 (Note 7)			
		±4.0 (Note 8)	mA		
		±3.0 (Note 9)			
	I _{OH} /I _{OL}	±1.7 (Note 10)			
		±0.3 (Note 11)			
		±0.02 (Note 12)			
Operating temperature	T _{opr}	-40~85	°C		
Input rise and fall time	dt/dV	0~10 (Note 13)	ns/V		

Note 5: $V_{CC} = 0V$

Note 6: High or Low state.

Note 7: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 8: $V_{CC} = 2.3 \sim 2.7 \text{ V}$

Note 9: $V_{CC} = 1.65 \sim 1.95 \text{ V}$

Note 10: $V_{CC} = 1.4 \sim 1.6 \text{ V}$

Note 11: $V_{CC} = 1.1 \sim 1.3 \text{ V}$

Note 12: $V_{CC} = 0.9 \text{ V}$

Note 13: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

TC7WG02FC



Electrical Characteristics

DC Electrical Characteristics

Characteristics	aracteristics Symbol Test Condition _F			Ta = 25°C			Ta = -40~85°C		Unit	
5,		V _{CC} (V)	Min	Тур.	Max	Min	Max	Onit		
					V _{CC}	_	_	V _C C	_	V
		_		1.1~1.3	V _{CC} × 0.7		_	V _{CC} × 0.7		
High-level V _{IH} input voltage	1.4~1.6			V _{CC} × 0.65		_	V _{CC} × 0.65			
	1.65~1.95			V _{CC} × 0.65	_	_	V _{CC} × 0.65	_		
				2.3~2.7	1.7	_	_	1.7	_	
				3.0~3.6	2.0		_	2.0		
					_		GND	_	GND	
				1.1~1.3	_		V _{CC} × 0.3	_	$\begin{array}{c} V_{CC} \\ \times \ 0.3 \end{array}$	
Low-level	V_{IL}		_			1	V _{CC} × 0.35		$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	V
input voltage					_		V _{CC} × 0.35	_	V _{CC} × 0.35	
					_	_	0.7		0.7	
				3.0~3.6	_	_	8.0		8.0	
			I _{OH} =-0.02 mA	0.9	0.75	_	_	0.75	_	
			$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V _{CC} × 0.75		_	V _{CC} × 0.75		
High-level VOH VOH	$V_{IN} = V_{IL}$	$I_{OH} = -1.7 \text{ mA}$	1.4~1.6	V _{CC} × 0.75		_	V _{CC} × 0.75		V	
		$I_{OH} = -3.0 \text{ mA}$	1.65~ 1.95	V _{CC} -0.45	_	_	V _{CC} -0.45			
			$I_{OH} = -4.0 \text{ mA}$	2.3~2.7	2.0	_	_	2.0	_	
			$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48	_	_	2.48	_	
Low-level V _{OL} V _{II}		$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1	V	
		I _{OL} = 0.3 mA	1.1~1.3		١	V _{CC} × 0.25		V _{CC} × 0.25		
	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 1.7 mA	1.4~1.6	_		V _{CC} × 0.25	_	V _{CC} × 0.25		
		I _{OL} = 3.0 mA	1.65~ 1.95	_	_	0.45	_	0.45		
		I _{OL} = 4.0 mA	2.3~2.7	_	_	0.4	_	0.4		
	I _{OL} = 8.0 mA		3.0~3.6	_	_	0.4	_	0.4		
Input leakage current	I _{IN}	V _{IN} = 0~5.5V		0~3.6	_	_	±0.1	_	±1.0	μА
Power off leakage current	l _{OFF}	V _{IN} = 0~5.5V V _{OUT} = 0~3.6V		0	_	_	1.0	_	10.0	μА
Quiescent supply current	Icc	V _{IN} = V _{CC} or GND		3.6	_	_	1.0	_	10.0	μА

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AC Electrical Characteristics (input $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
Characteristics	Symbol	rest Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
		C _L = 10 pF,	0.9	_	19.8	_	_	_	-
			1.1~1.3	_	10.1	18.7	1.0	34.5	
			1.4~1.6	_	5.9	8.9	1.0	10.8	
		$R_L = 1 M\Omega$	1.65~ 1.95	_	4.5	6.4	1.0	6.9	
			2.3~2.7	_	3.1	4.2	1.0	4.7	ns
			3.0~3.6		2.3	3.4	1.0	4.0	
		C_L = 15 pF, R_L = 1 $M\Omega$	0.9		22.5	_			
	^t pLH ^t pHL		1.1~1.3		11.6	21.5	1.0	37.2	
Propagation delay time			1.4~1.6		6.6	9.8	1.0	12.0	
1 Topagation delay time			1.65~ 1.95		5.0	7.1	1.0	7.3	
			2.3~2.7		3.5	4.5	1.0	5.1	
			3.0~3.6		2.8	3.8	1.0	4.4	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9		30.0	_			
			1.1~1.3		15.0	29.6	1.0	56.0	
			1.4~1.6		8.5	13.1	1.0	15.9	
			1.65~ 1.95	_	6.3	9.2	1.0	9.6	
			2.3~2.7		4.3	5.7	1.0	6.1	
			3.0~3.6	_	3.5	4.4	1.0	4.8	
Input capacitance	C _{IN}	_	3.6	_	3	_	_	_	pF
Power dissipation capacitance	C _{PD}	(Note 14)	0.9 ~ 3.6	_	11	_		_	pF

Note 14:C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

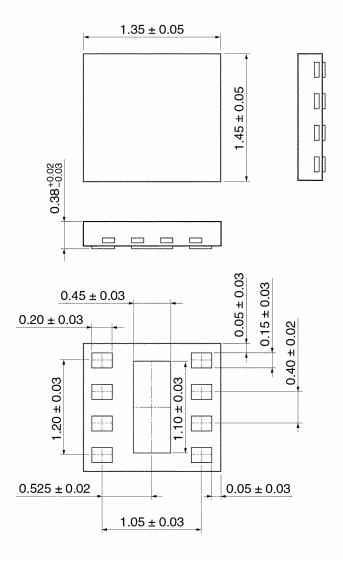
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Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$

Package Dimensions

CSON8-P-0.4 Unit: mm



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Weight: 0.002 g (typ.)

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20070701-EN GENERAL

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